Multi output OSC

MG7050EAN

Product name MG7050EAN 100.000000MHz 2ACJDN Product Number / Ordering code X1M0004110014xx

Please refer to the 10.Packing information about xx (last 2 digits)

Output waveform LV-PECL

Pb free / Complies with EU RoHS directive

Reference weight Typ. 163 mg

1.Absolute maximum ratings							
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions / Remarks	
Maximum supply voltage	Vcc-GND	-0.5	-	4	V		
Storage temperature	T_stg	-55	-	125	°C	Storage as single product	
Input voltage	Vin	-0.5	-	Vcc+0.5	V	ST or OE terminal	

2.Specifications(characte	eristics)							
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions / Remarks		
Output frequency	f0		100.0000		MHz	2 output		
Supply voltage	Vcc	2.97	3.3	3.63	V			
Operating temperature	T_use	-5	-	85	°C			
Frequency tolerance	f_tol	-50	-	50	x10 ⁻⁶	T_use		
Current consumption	Icc	-	80	102	mA	L_ECL=50Ω		
Stand-by current	I_std	-	-	-	mA	-		
Disable current	I_dis	-	8	20.0	mA	OE=GND		
Symmetry	SYM	45	-	55	%	At output crossing point		
Output voltage(LV-PECL)	V _{OH}	Vcc-1.025	-	Vcc-0.88	V	DC characteristics		
	V_{OL}	Vcc-1.81	-	Vcc-1.62	V			
Output load condition(ECL)	L_ECL	-	50	-	Ω	Terminated to Vcc-2.0V		
Input voltage	V_{IH}	70%Vcc	-	-		OE ans FAEL terminal		
	V_{IL}	-	-	30%Vcc				
Rise time	t _r	-	200	400	ps	Between 20% and 80% of (VOH-VOL)		
Fall time	tf	-	200	400	ps	Between 20% and 80% of (V _{OH} -V _{OL})		
Start-up time	t_str	-	5	10	ms	Time at minimum supply voltage to be 0		
Jitter	t _{DJ}	-	-	N/A	ps	Deterministic Jitter		
	T_{RJ}	-	-	N/A	ps	Random Jitter		
	t _{RMS}	-	-	N/A	ps	σ(RMS of total distribution)		
	t _{p-p}	-	-	N/A	ps	Peak to Peak		
	t _{acc}	-	-	N/A	ps	Accumulated jitter		
Phase jitter	t _{PJ}	-	0.14	0.3	ps	Offset frequency 12 kHz to 20 MHz		
Phase noise	L(f)	-	-	-	dBc/Hz	Offset:1 Hz		
		-	-58.8	-	dBc/Hz	Offset:10 Hz		
		-	-87.9	-	dBc/Hz	Offset:100 Hz		
		-	-118.1	-	dBc/Hz	Offset:1 kHz		
		-	-146.1	-	dBc/Hz	Offset:10 kHz		
		-	-153.7	-	dBc/Hz	Offset:100 kHz		
		-	-156.4	-	dBc/Hz	Offset:1 MHz		
Skew	t_skew	-	-	50	ps	FSEL = H		
Frequency aging	f_age	-10	-	10	x10 ⁻⁶ /Year	@+25°C first year		
		-	-	-		-		

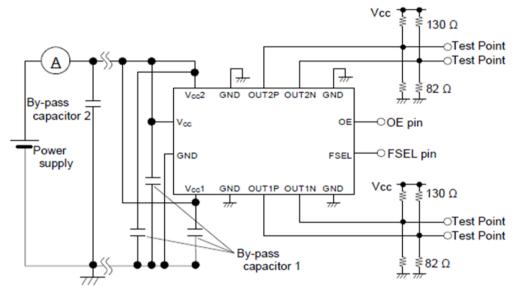
3.Test circuit

1) Measurement condition

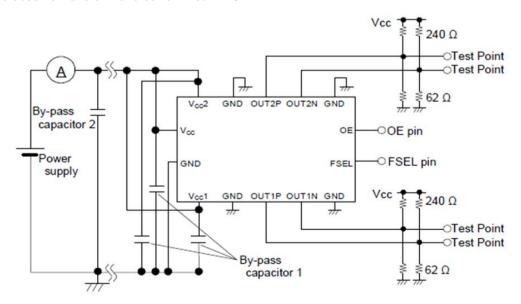
- (1) Oscilloscope
 - · Bandwidth should be 5 times higher than DUT's output frequency (4 GHz).
 - Probe ground should be placed closely from test point and lead length should be as short as possible.
- (2) By-pass capacitor 1 (approx. 0.01 µF to 0.1 µF) places closely between Vcc and GND.
- (3) By-pass capacitor 2 (approx. 10 µF) places closely between power supply terminals on the board.
- (4) Use the current meter whose internal impedance value is small.
- (5) Power supply
- Start up time (0 V→90 %Vcc) of power source should be more than 150 µs and slew rate should be less than 19.8 mV/µs.
- Impedance of power supply should be as low as possible.

2) 2 outputs type

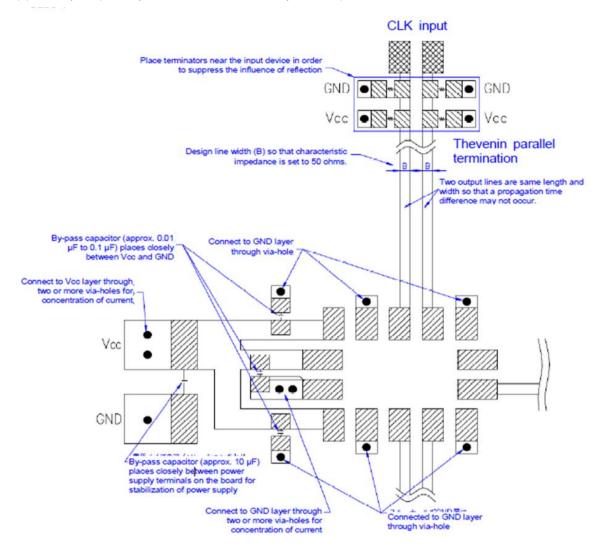
(1)To observe waveform and current Vcc = 3.3V



(2)To observe waveform and current Vcc = 2.5V

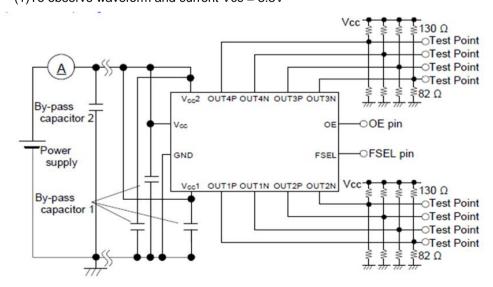


(3)PCB layout (multilayers, with Vcc and GND layer inside)

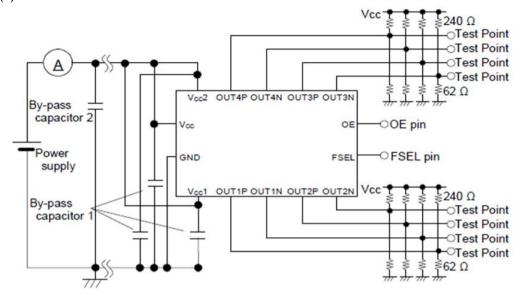


3) 4 outputs type

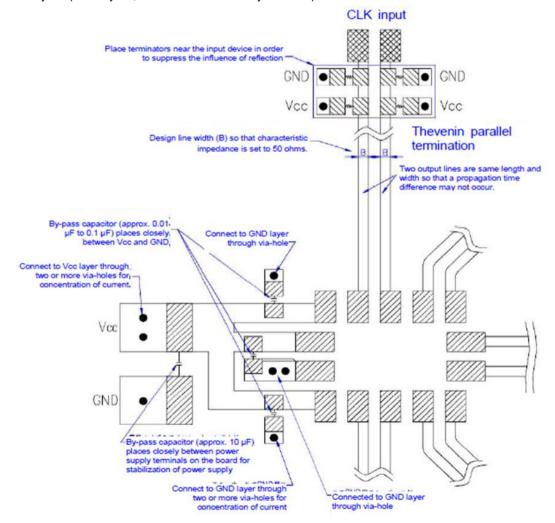
(1)To observe waveform and current Vcc = 3.3V



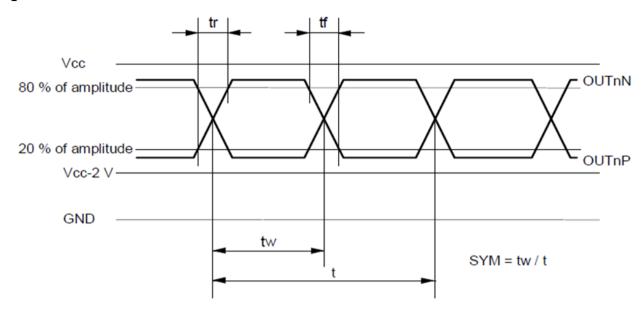
(2)To observe waveform and current Vcc = 2.5V

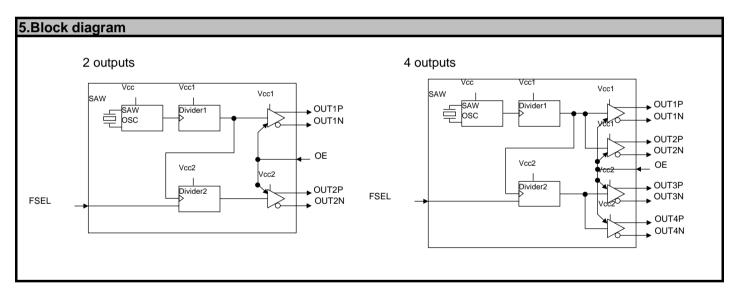


(3)PCB layout (multilayers, with Vcc and GND layer inside)

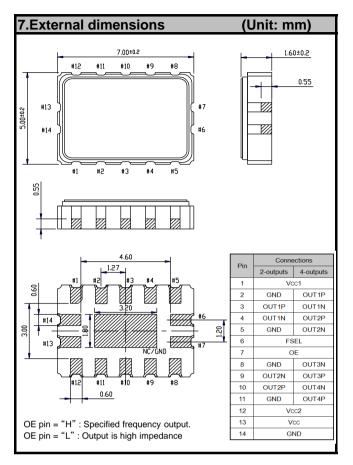


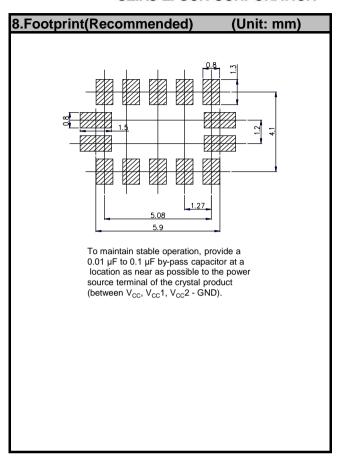
4.Timing chart

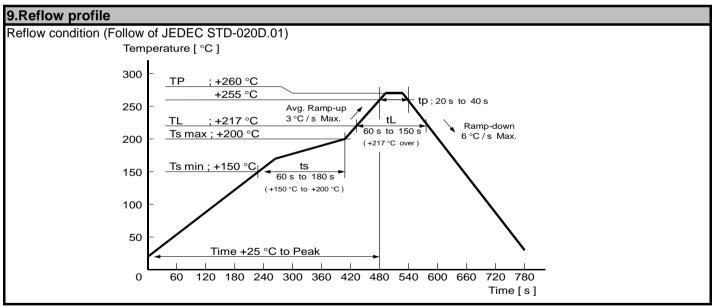




SEL function				
Г	2-out	tputs	OUT1	OUT2
	4-outputs		OUT1 / OUT2	OUT3 / OUT4
	FSEL	Н	fo	fo
	FOEL	L	fo	fo/2







Unit: mm

10.Packing information

[1]Product number last 2 digits code(xx) description

The recommended code is "00"

X1M0004110014xx

Code	Condition	Code	Condition
01	Any Q'ty vinyl bag(Tape cut)	13	500pcs / Reel
11	Any Q'ty / Reel	00	1000pcs / Reel
12	250pcs / Reel		

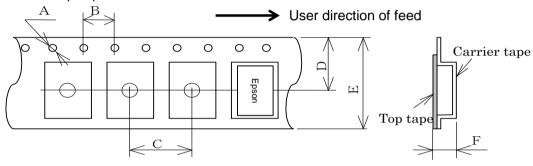
[2] Taping specification

Subject to EIA-481 & IEC-60286

(1) Tape dimensions

Material of the Carrier Tape : PS

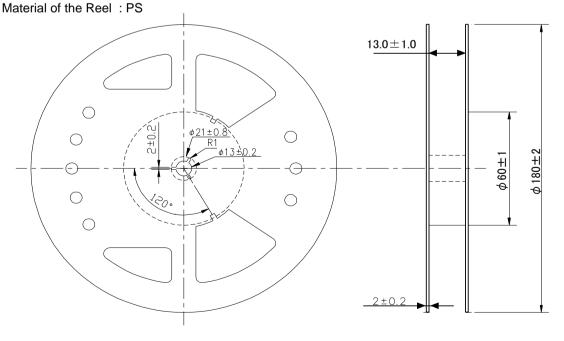
Material of the Top Tape : PET+PE



Symbol	Α	В	C	D	Ш	F
Value	Ф1.5	4	8	9.25	16	2.3

(2) Reel dimensions

Center material : PS



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